### T3226 / T0864 COMPUTER ORGANIZATION

## T.E. ETRX Sem VI CBSGS



Time: 3 Hours	Marks: 80
N.B: (1) Question No.1 is compulsory.	
(2) Attempt any three questions from remaining questions.	
(3) Figures to the right indicate full marks.	
Q1(a)Multiply using Booth's algorithm (-7) * (3).	5
(b) Explain parallel processing.	5
(c) Write a note on IA-32 register model.	5
(d) Compare Horizontal and Vertical organization.	80 5 8 8 8 5
Q2(a)What is cache coherency? Explain various methods to achieve it.	10
(b) Explain microprogramming. Draw and explain microprogrammed control un	nit. 10
Q3.(a) Consider a 4-way set associative Cache Mapping with Cache Block Size=16	bytes
Cache size=8k,Main Memory Size =64k. Design a cache structure and show	v how the
Processor address is interpreted.	10
(b) Why is page replacement algorithm required. Explain how pages are replaced	d between
cache and main memory using replacement policies.	10
Q4 (a) Explain various access methods for I/O devices.	10
(b)Explain how a virtual address is converted into physical address using paging	.Also
explain Translation Look- aside Buffer.	10
Q5 (a) Explain with examples different addressing modes of IA-32.	10
(b) Write microinstructions for the instruction Add R <sub>0</sub> , [R <sub>3</sub> ].	5
(c)Explain in brief about Nanoprogramming.	5
Q6(a)Write a note on Flynn's classification.	10
(b) Explain the Hazards in Pipelining and solutions to overcome them	10

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Tem VI CBGS Electronics

Q.P. Code:18380

#### (2 Hours)

Q.1 is compulsory

#### **Total Marks-40**

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Attempt any three questions from remaining five. ii. Each question carries 10 marks. iii. 1. Answer any five. a. What is structured cabling? b. What is web server? c. Explain CIA triangle in brief. d. Write four good practices used for password management. e. What is Ethernet? What is Biometric system? Explain it. g. State Network topologies. 2. a. What is a firewall? Differentiate among the different types of firewall. 5 b. Explain Enterprise resource planning (ERP) and its need. 5 3. a. Why is Audit needed and what is the planning required for conducting Audit? 5 5 b. Differentiate between DBMS and RDBMS. 4. a. Explain the term business process outsourcing (BPO). 5 b. What is the need of intranet in an organization? State the benefits. 5 5. 5 What is HTTP and what is its purpose? b. What is e-business? Differentiate it with e-commerce. 6. Define operating system. Explain different types of operating system. 5 b. State different types of cable? Explain fiber optic cable in brief. 5

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Sem VI CB95 Dectronics

(3 Hours)

[Total Marks: 80]

Q.P.Code: 016380

#### NB:

- 1) Question No. ONE is compulsory.
- 2) Out of remaining questions, attempt any THREE questions.
- 3) In all FOUR questions to be attempted.
- 4) All questions carry equal marks.
- 5) Answer to each new question to be started on a fresh page.
- 6) Figures in brackets on the right hand side indicate full marks.
- 7) Assume Suitable data if necessary

#### Q1. Attempt any four

(20 marks)

- a) State and explain relation between DTFS, DFT and ZT
- b) Explain the need of DSP processor.
- c) Differentiate between Butterworth and Chebyshev filters.
- d) Explain frequency wrapping effect in designing IIR filter.
- e) Compare DSP processor and microprocessor.
- Q2. a) Explain Gibbs Phenomenon and state its significance in FIR filter design.

(10 marks)

b) Explain different addressing modes of TMS 320C67XX DSP processor.

(10 marks)

Q3. a) What are the salient features of TMS 32067C67XX family of DSP processors.

(10 marks)

- b) Compute the circular convolution of the sequence using DFT and IDFT, x1(n)={1,2,0} and x2(n)={2,2,1,1} (10 marks)

(10 marks)

b) Explain V-LIW architecture in details

(10 marks)

Q5. a) Design Butterworth LPF to meet following specifications

Passband gain is 0.89

Passband frequency edge 30Hz

Attenuation 0.20

Stopband edge 75Hz

(10 marks)

- b) Design analog Butterworth filter that has -2 dB passband attenuation of 20 rad/sec and at least -10 dB stopband attenuation at 30 rad/sec.
   (10 marks)
- Q6. Write short note on following (Any two)

(20 marks)

- a) Frequency transformation in IIR filter
- b) Application of DSP in speech and Radar processing
- c) Limit cycle Oscillations

# 2/06/17

#### T3226 / T0865 POWER ELECTRONICS I

TE-ETRX (CBSGS) Sem-V



20

# REVISED COURSE

Total Marks: 80

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CBSGS.

1) Question No-1 is Com
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- 2) Attempt any Three (03) Questions from remaining Five (05) Questions
- 3) Assume suitable data where ever necessary.

1.	Attempt the following Questions (any4)	
1.	a) Draw the Two Transistor Model Of SCR? State all the currents Equations of IC <sub>1</sub> , IC <sub>2</sub>	5
	&,I <sub>A</sub>	5
	b) Why forced commutation is required in DC to AC converters.	5
	c) Calculate output voltage for a step down chopper with Vin=200 V and Duty Cycle =0.25	5
	d) What is the Need of freewheeling diode in rectifiers state with example	5
	<ul><li>e) Explain brief why harmonic Neutralization is necessary in output of inverter.</li><li>f) Define and explain performance parameter of controlled rectifier</li></ul>	5
2. (a)	What do you mean by Commutation of SCR? State the various methods of commutation of SCR, Explain force method in detail.	10
(b)	What is difference between a cycloconverter and an ac voltage controller, Explain single phase converters with waveforms	10
3. (a)	Explain the Basic Structure& static characteristics of IGBT with creation of inversion layer &conductivity modulation	10
(b)	Draw and Explain Buck-Boost Converter with the help of circuit diagram and waveforms Derive the relation for load voltage.	10
4. (a)	A three phase bridge inverter is operated in 180° conduction mode is operating from a 560V DC supply ,Find out the following (I)RMS Value of output line and phase voltage (II)RMS Value of fundamental components of line and phase Voltages	10
(b)	Explain the Static I-V Characteristics of TRIAC? State Forward and Reverse Characteristics, Compare DIAC-TRIAC.	10
5. (a)	Why the protection of SCR in Necessary? State the various protection of SCR, Explain any one method in detail.	10
(b)	State comparison between control strategies of chopper 1.PWM control 2.Varable Frequency Conrol 3.Current limit control. A step down chopper feeds a resistive load of 10 ohms from 100V DC supply .Calculate duty cycle required so that power dissipation in load is 100watts	10

#### 6. Write short note on (any 4):

- (a) Half wave controlled rectifiers with R load with waveforms
- (b) full bridge inverter with waveforms
- (c) Cuk regulators
- (d) Construction& operation of GTO
- (e) Compare IGBT and Power BJT

#### T3226 / T0863 ADVANCED INSTRUMENTATION SYSTEM



Q.P. Code :08431

#### [Time: 3 Hours]

[Marks:80]

Please check whether you have got the right question paper.

N.B:

- 1. Question no. 1 is compulsory.
- 2. Attempt any three questions from the remaining five questions.
- 3. Assume suitable data whenever necessary.
- 4. Figure to the right indicate full marks.

			130 0
Q.1	Explain	in brief	100 CO.
	a)	Integral controller	05
	b)	Temperature transmitter	<b>O</b> 5
	c)	Telemetry Section 1997	05
	d)	I-P converter	<b>O</b> 5
Q.2	a)	What are the different types of control valve actuators? Explain the working of any two	10
8		actuators in detail.	10
	b)	What are the different types of hydraulic pumps? Explain with neat sketch	10
Q.3	a)	Explain loading of valves in pump application with diagram.	10
	b)	Explain control valve characteristics. An equal percentage valve has maximum flow of 50cm <sup>3</sup> /s	10
		and a minimum of 2cm <sup>3</sup> /s. If the full travel is 3cm; find the flow at a 1 cm opening.	
Q.4	a)	Explain in details construction and working of time delay valve.	10
	b)	What are the different applications of a flapper nozzle system? With neat diagram explain the	10
		flapper nozzle system and its characteristics.	
Q.5		Explain the need of controller tuning. What are the different methods of controller tuning?	10
	b)	Explain compressed air receiver unit. What are the different control strategies for air receiver	10
	XX.0%	unit?	
Q.6	(e (a)	Compare conventional and smart transmitters. Explain the working of DP transmitter.	10
200 C	b)	Write short note on:	10
8 5 5 E	2003	i. Data logger	
2000	25	2. 4. 4. 5. 8. 6. 4. 2. 6. 1 · · · · · · · · · · · · · · · · · ·	

Pressure regulation valve.

# TE SOM VI ETRX (BGS) Basic VLSI Design Q.P.

[Time: 3 Hours]

		Please check whether you have got the right question paper.	7.00° E
	N.B:	1. Question No. 1 is compulsory.	28200
		2. Attempt any three questions from remaining five questions.	120g
		3. Assume suitable data where required.	000
		4. Figures to the right indicate full marks.	2010
			2000
	V Dedication (Sec. Proc		20.3
Q.1	A TOTAL OF THE PARTY OF THE PAR	\$\$\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	5,7,6
	a] Compare NM	10S & CMOS technology in VLSI design 3 5 7 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5	3. J.
	of implement th	he following function using Dynamic CMO slogic 20 20 20 20 20 20 20 20 20 20 20 20 20	000
		Y=A(B+C) などくろとんくらとからからにあるかだいのか	0
	c] Compare Ripp	ple carry adder with CLA.	525
	d] Explain worki	ing Principle of flash memory 2000 000 0000 0000 0000 0000 00000	0
	e] Explain impor	rtance of low power designs 3000000000000000000000000000000000000	0
			0.
Q.2	a] Compare the	full scaling & constant voltage scaled 5 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	
	on the area, dela	full scaling & constant voltage scaling models of MOSFETS. Demonstrate the effects of scaling power consumption and current density of the device	ng 10
	b] Explain transf	er characteristics for MMOCOLING TEACHER OF THE device	
	in W/L ratio?	er characteristics for NMOS. Inverter showing different regions. What is the effect of variati	on 10
		08200253342838254900000	
Q.3	a] Draw 1T DRAM	of cell and explain it's write, read, hold & refresh operation.	
	b] Explain schem	e for multiplication of 101*010	10
		935 10 5 3 5 1 1 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5	10
Q.4	al Explain various		
Contract Con	bl Consider a CN	steehniques of clock generation & clock distribution.	10
	Vnn= 3.300	as mixer tel circult with following parameters	10
	$V_{DD} = 3.3 \times 10^{-3}$ $V_{TQ} = 0.6 \times 10^{-3}$	<b>F. S. F. B. B.</b>	
	VT0.p= 0.7		
	Kn=200 µ	2 NOTE - STANDED OF OR STANDED OF	
	$N_p = 80 \mu$	1 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	
	Calculate noise M	Paralle of the Asia and Asia a	
	26,21,20,30	or single circuit consider $K_R = 2.5 \otimes V_{To,n} \neq V_{To,p}$ .	
0.50	at Dearwing run ru		
3.0	a) profes in Lib tio	p using CMOS and explain the working.	10
327	Characa Cra Icari	y lookahead adder) carry chain using dynamic CMOS logic.	10
Carles.	The Colored States	\$6.67 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	10
600	Write Short notes	on (any three)	
C .	all arthum in CM		20
198	b) Sense Amplifier	9,9,0,0,0,0,0,0	
8	interconnect sca	11080,0,0,0,0,0	